

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	22.6239	N/A	2.9555
RT2	5.5371	N/A	9.6714
RT3	19.6198	N/A	5.2818
RT4	47.2192	N/A	4.0913
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	5.2942 m	N/A	350.5225 m
CT2	413.1296 u	N/A	1.7526 m
CT3	71.8083 m	N/A	3.1424 m
CT4	1.6731	N/A	211.0064 u

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	5.3231	N/A	7.0820
RF2	24.3905	N/A	7.7875
RF3	18.9915	N/A	4.6993
RF4	46.2949	N/A	2.4312
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	292.3487 μ	N/A	227.8687 μ
CF2	3.9300 m	N/A	1.0478 m
CF3	57.3517 m	N/A	1.8691 m
CF4	1.6058	N/A	534.9725 m

Note

NA indicates not applicable

